NSN 5961-01-113-5980

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Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-113-5980 **Inclosure Material:** Metal **Overall Length:** Between 0.160 inches and 0.180 inches **Terminal Length:** Between 0.985 inches and 1.015 inches **Overall Diameter:** Between 0.355 inches and 0.366 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-5 **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case and mounting hardware **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 250.0 repetitive peak reverse voltage, peak total value and 200.0 repetitive peak reverse voltage and 200.0 off-state voltage, rms total **Current Rating Per Characteristic:** 1.00 amperes forward current, average **Power Rating Per Characteristic:** 0.5 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius ambient air **Test Data Document:** 13973-841090 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No